

MAX2602ESA

MAX2602ESA Information

a certain a second a	 MAX2602ESA Maxim Integrated Discrete Semiconductor Products Transistors - Bipolar (BJT) - RF TRANS RF NPN 900MHZ 15V 8SOIC 8-SOIC (0.154", 3.90mm Width) Exposed Pad For the pricing/inventory/lead time, please contact	
For Reference Only	Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



MAX2602ESA Specifications

Manufacturer Part Number	MAX2602ESA	
Manufacturer	Maxim Integrated	
Category	Discrete Semiconductor Products	
	Transistors - Bipolar (BJT) - RF	
Package	8-SOIC (0.154", 3.90mm Width) Exposed Pad	
Series	-	
Transistor Type	NPN	
Voltage - Collector Emitter Breakdown (Max)	15V	
Frequency - Transition	1GHz	
Noise Figure (dB Typ @ f)	3.3dB @ 836MHz	
Gain	11.6dB	
Power - Max	6.4W	
DC Current Gain (hFE) (Min) @ Ic, Vce	100 @ 250mA, 3V	
Current - Collector (Ic) (Max)	1.2A	
Operating Temperature	150°C (TJ)	
Mounting Type	Surface Mount	
Package / Case	8-SOIC (0.154", 3.90mm Width) Exposed Pad	
Supplier Device Package	8-SOIC-EP	
	Report errors?	

MAX2602ESA Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE BUARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

MAX2602ESA Payment Methods



MAX2602ESA Shipping Methods



If you have any question about MAX2602ESA, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com